



100V N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

V _{(BR)DSS}	R _{DS(on) max}	I _D T _C = +25°C
100V	80mΩ @ V _{GS} = 10V	17A
	99mΩ @ V _{GS} = 6V	15A

Description

This new generation complementary MOSFET features low on-resistance and fast switching, making it ideal for high efficiency power management applications.

Applications

- Power Management Functions
- DC-DC Converters

Features

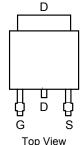
- Low R_{DS(ON)} ensures on state losses are minimized
- Small form factor thermally efficient package enables higher density end products
- Lead-Free Finish; RoHS compliant (Note 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

- Case: TO252 (DPAK)
- Case Material: Molded Plastic, "Green" Molding Compound UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin annealed over Copper leadframe Solderable per MIL-STD-202, Method 208 ³
- Weight: 0.33 grams (approximate)









Internal Schematic

D

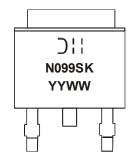
Ordering Information (Note 4)

Part Number	Case	Packaging
DMN10H099SK3-13	TO252	2,500/Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



Oli = Manufacturer's Marking
N099SK = Product Type Marking Code
YYWW = Date Code Marking
YY = Last Digit of Year (ex: 14 = 2014)
WW = Week Code (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units	
Drain-Source Voltage		V _{DSS}	100	V
Gate-Source Voltage	V_{GSS}	±20	V	
Continuous Drain Current (Note 5) V _{GS} = 10V	T_C = +25°C T_C = +70°C	I _D	17 13	А
Pulsed Drain Current (10µs pulse, duty cycle = 1%)	I _{DM}	20	A	
Avalanche Current, L = 1mH	I _{AS}	7.5	Α	
Avalanche Energy, L = 1mH	E _{AS}	28.5	mJ	

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Units
Total Power Dissipation (Note 5)	T _C = +25°C	Б	34	- W
Total Power Dissipation (Note 5)	T _C = +70°C	P _D	22	
Thermal Resistance, Junction to Ambient (Note 5)	R _{0JA}	51	°C/W	
Thermal Resistance, Junction to Case (Note 5)		Rejc	3.6	C/VV
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C

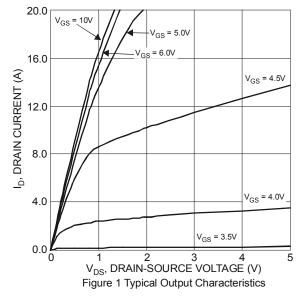
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

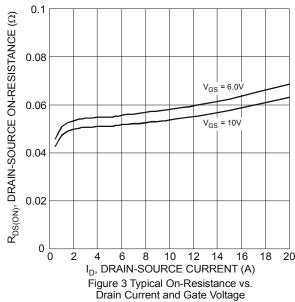
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	100	_	_	V	V _{GS} = 0V, I _D = 250μA	
Zero Gate Voltage Drain Current	I _{DSS}	_	_	1	μA	V _{DS} = 80V, V _{GS} = 0V	
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	V _{GS} = ±20V, V _{DS} = 0V	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(th)}	1.5	2	3	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$	
Static Drain-Source On-Resistance	J		67	80	mΩ	V _{GS} = 10V, I _D = 3.3A	
Static Dialii-Source Oil-Resistance	R _{DS (ON)}	_	69	99	11122	$V_{GS} = 6V$, $I_D = 3A$	
Diode Forward Voltage	V_{SD}	_	0.77	_	V	V _{GS} = 0V, I _S = 3.2A	
DYNAMIC CHARACTERISTICS (Note 6)							
Input Capacitance	C _{iss}		1172	_		V _{DS} = 50V, V _{GS} = 0V, f = 1MHz	
Output Capacitance	Coss		40.8	_	pF		
Reverse Transfer Capacitance	C _{rss}		31.3	_			
Gate Resistance	R_{G}		1.6	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (V _{GS} = 10V)	Q_g		25.2	_			
Total Gate Charge (V _{GS} = 4.5V)	Q_g	_	12.2	_	nC	V _{DS} = 50V, I _D = 3.3A	
Gate-Source Charge	Q_{gs}	_	5.3	_	iiC		
Gate-Drain Charge	Q_{gd}	_	5.9	_			
Turn-On Delay Time	t _{D(on)}	_	5.4	_		$V_{DD} = 50V$, $R_G = 6.0\Omega$, $I_D = 3.3A$	
Turn-On Rise Time	t _r	_	5.9	_	20		
Turn-Off Delay Time	t _{D(off)}	_	20	_	ns		
Turn-Off Fall Time	t _f	_	7.3	_			
Body Diode Reverse Recovery Time	t _{rr}		19.7	_	ns	L = 2.24 d1/dt = 4004/	
Body Diode Reverse Recovery Charge	Q _{rr}	_	15.9		nC	I _F = 3.3A, dl/dt = 100A/μs	

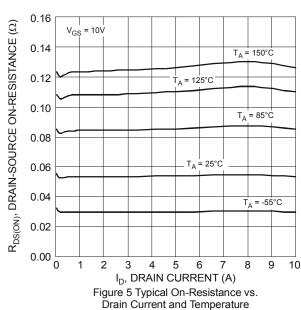
5. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. Notes:

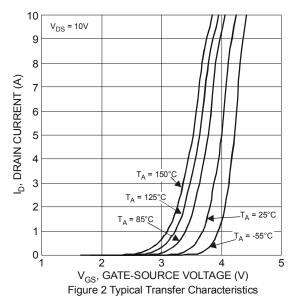
Guaranteed by design. Not subject to product testing.
 Short duration pulse test used to minimize self-heating effect.

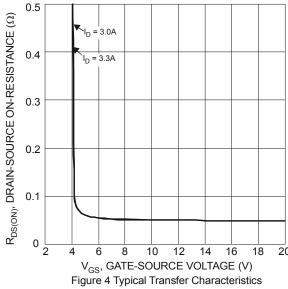












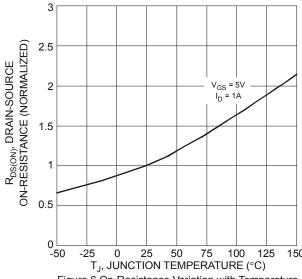
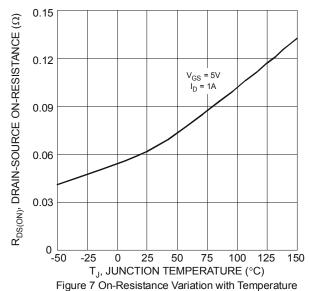
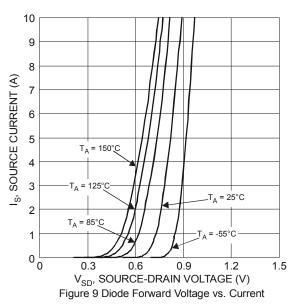
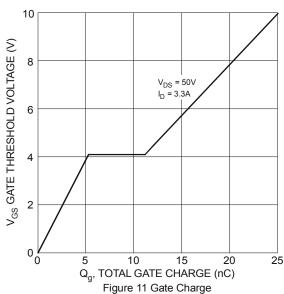


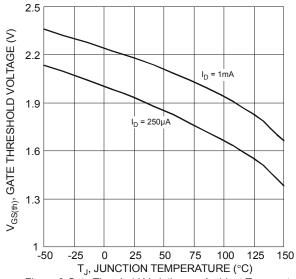
Figure 6 On-Resistance Variation with Temperature



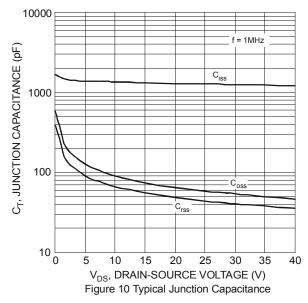








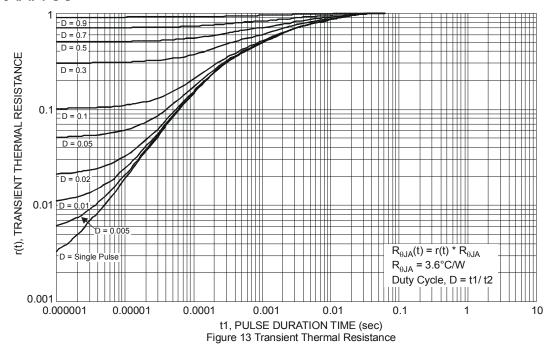




100
R_{DS(on)}
Limited
P_W = 1µs

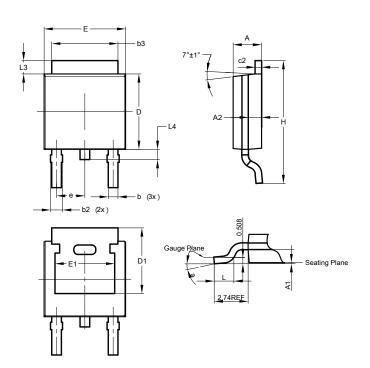
10
P_W = 100ms
P_W = 100ms
P_W = 100µs
P_W =





Package Outline Dimensions

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for latest version.

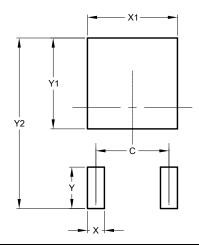


TO252 (DPAK)					
Dim	Min	Max	Тур		
Α	2.19	2.39	2.29		
A 1	0.00	0.13	0.08		
A2	0.97	1.17	1.07		
b	0.64	0.88	0.783		
b2	0.76	1.14	0.95		
b3	5.21	5.46	5.33		
c2	0.45	0.58	0.531		
D	6.00	6.20	6.10		
D1	5.21	-	-		
е	-	-	2.286		
Е	6.45	6.70	6.58		
E1	4.32	-	-		
Ξ	9.40	10.41	9.91		
L	1.40	1.78	1.59		
L3	0.88	1.27	1.08		
L4	0.64	1.02	0.83		
а	0°	10°	-		
All Dimensions in mm					



Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)		
С	4.572		
Х	1.060		
X1	5.632		
Υ	2.600		
Y1	5.700		
Y2	10.700		

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